

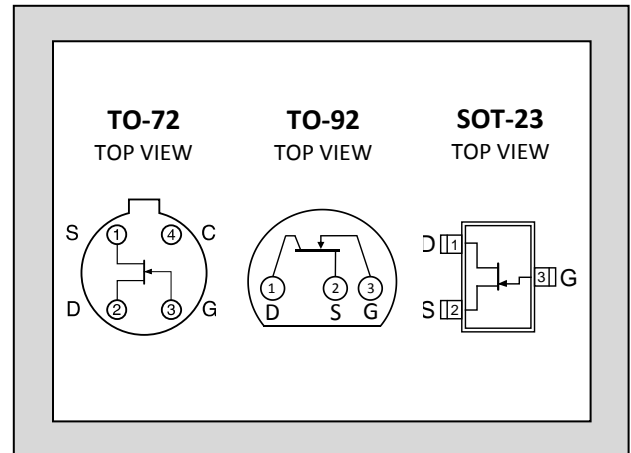
LINEAR SYSTEMS

Over Three Decades of Quality Through Innovation

LS846

LOW NOISE LOW LEAKAGE
SINGLE N-CHANNEL
JFET AMPLIFIER

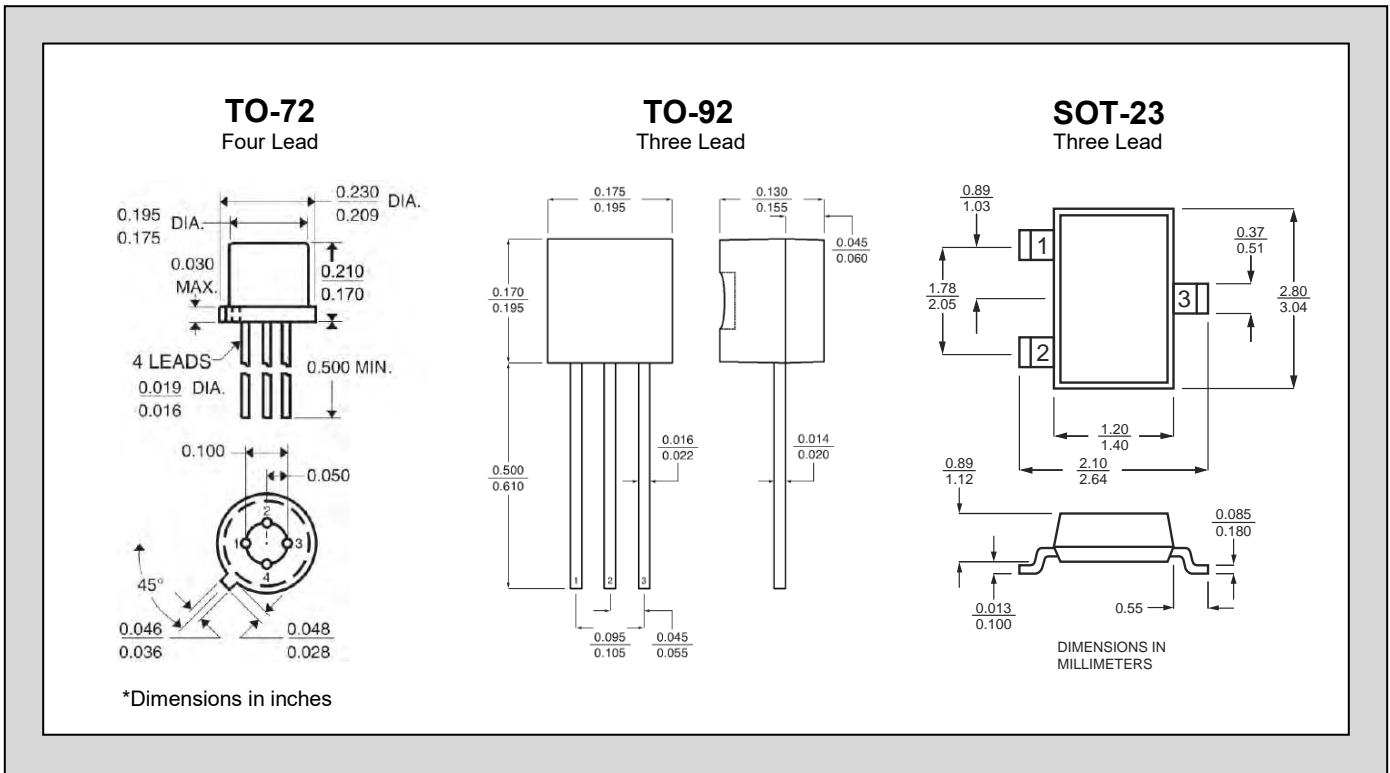
| FEATURES | |
|--|-------------------------------------|
| ULTRA LOW NOISE | $e_n = 3\text{nV}/\sqrt{\text{Hz}}$ |
| LOW INPUT CAPACITANCE | $C_{iss} = 4\text{pF}$ |
| ABSOLUTE MAXIMUM RATINGS¹ @ 25 °C (unless otherwise stated) | |
| Maximum Temperatures | |
| Storage Temperature | -55 to +150°C |
| Operating Junction Temperature | -55 to +150°C |
| Maximum Power Dissipation | |
| Continuous Power Dissipation TA=25°C | 300mW ³ |
| Maximum Currents | |
| Gate Forward Current | $I_{G(F)} = 10\text{mA}$ |
| Maximum Voltages | |
| Gate to Source | $V_{GSO} = 60\text{V}$ |
| Gate to Drain | $V_{GDO} = 60\text{V}$ |



*For equivalent Monolithic Dual, see LS843 Family

| SYMBOL | CHARACTERISTIC ² | MIN | TYP | MAX | UNITS | CONDITIONS |
|---------------|---|------|------|------|------------------------------|--|
| BV_{GSS} | Gate to Source Breakdown Voltage | -60 | | | V | $V_{DS} = 0, I_D = 1\text{nA}$ |
| $V_{GS(OFF)}$ | Gate to Source Pinch-off Voltage | -1 | | -3.5 | V | $V_{DS} = 15\text{V}, I_D = 1\text{nA}$ |
| V_{GS} | Gate to Source Operating Voltage | -0.5 | | -3.5 | V | $V_{DS} = 15\text{V}, I_D = 500\mu\text{A}$ |
| I_{DSS} | Drain to Source Saturation Current | 1.5 | 5 | 15 | mA | $V_{DS} = 15\text{V}, V_{GS} = 0$ |
| I_G | Gate Operating Current | | -15 | -50 | pA | $V_{DG} = 15\text{V}, I_D = 500\mu\text{A}$ |
| I_G | Gate Operating Current Reduced V_{DG} | | -5 | -30 | pA | $V_{DG} = 3\text{V}, I_D = 500\mu\text{A}$ |
| I_{GSS} | Gate to Source Leakage Current | | | -100 | pA | $V_{GS} = 15\text{V}, V_{DS} = 0$ |
| G_{fss} | Full Conductance Transconductance | 1500 | | | μS | $V_{DS} = 15\text{V}, V_{GS} = 0, f = 1\text{kHz}$ |
| G_{fs} | Typical Operation Transconductance | 1000 | 1500 | | μS | $V_{DS} = 15\text{V}, I_D = 200\mu\text{A}$ |
| G_{OSS} | Full Output Conductance | | | 40 | μS | $V_{DS} = 15\text{V}, V_{GS} = 0$ |
| G_{OS} | Typical Operation Output Conductance | | 2.0 | 2.70 | μS | $V_{DS} = 15\text{V}, I_D = 200\mu\text{A}$ |
| NF | Noise Figure | | | 0.5 | dB | $V_{DS} = 15\text{V}, V_{GS} = 0, R_G = 10\text{M}\Omega, f = 100\text{Hz}, \text{NBW} = 6\text{Hz}$ |
| e_n | Noise Voltage | | 3 | 7 | $\text{nV}/\sqrt{\text{Hz}}$ | $V_{DS} = 15\text{V}, I_D = 500\mu\text{A}, f = 1\text{kHz}, \text{NBW} = 1\text{Hz}$ |
| e_n | Noise Voltage | | | 11 | $\text{nV}/\sqrt{\text{Hz}}$ | $V_{DS} = 15\text{V}, I_D = 500\mu\text{A}, f = 10\text{Hz}, \text{NBW} = 1\text{Hz}$ |
| C_{iss} | Common Source Input Capacitance | | 4 | 8 | pF | $V_{DS} = 15\text{V}, I_D = 500\mu\text{A}, f = 1\text{MHz}$ |
| C_{RSS} | Common Source Reverse Transfer Cap. | | | 3 | pF | |

STANDARD PACKAGE DIMENSIONS:



NOTES:

1. Absolute maximum ratings are limiting values above which serviceability may be impaired.
2. All MIN/TYP/MAX limits are absolute numbers. Negative signs indicate negative electrical polarity only.
3. Derate 2.8mW/°C above 25°C.

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